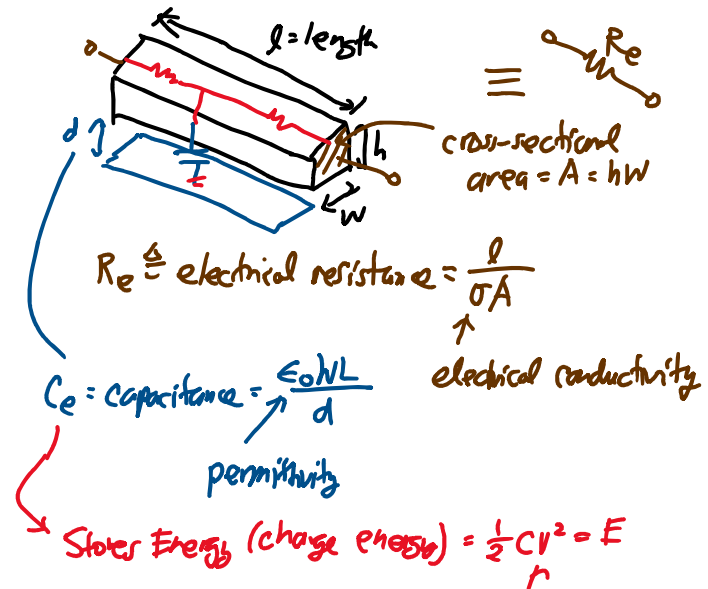


Lecture 4: Benefits of Scaling III

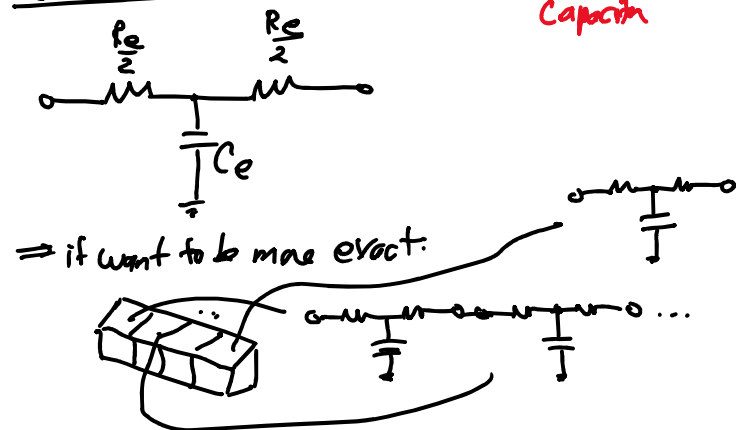
- Announcements:
- Modules 1 & 2 are online
- HW#1 online and due Feb. 11 at 8 a.m.
- Will go longer today by about 20 minutes or so to make up a bit for the lecture lost on first day
- Will do this a few more times until we're caught up
-
- Today:
- Reading: Senturia, Chapter 1
- Lecture Topics:
 - ↳ Benefits of Miniaturization
 - ↳ Examples
 - GHz micromechanical resonators
 - Chip-scale atomic clock
 - Micro gas chromatograph
-
- Last Time:
- Going through Module 2, looking at Chip-Scale Atomic Clock
- Continue with this now

Review Electrical Resistive First

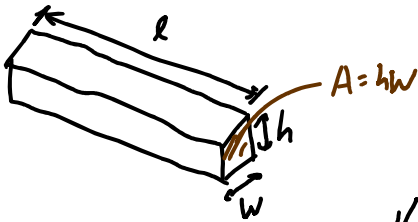
(then attack the thermal R analogy)



Equivalent Ckt.



Thermal Ckt.



$A = hw$

⇒ thermal capacitance: $C_{th} = \rho V C_p$

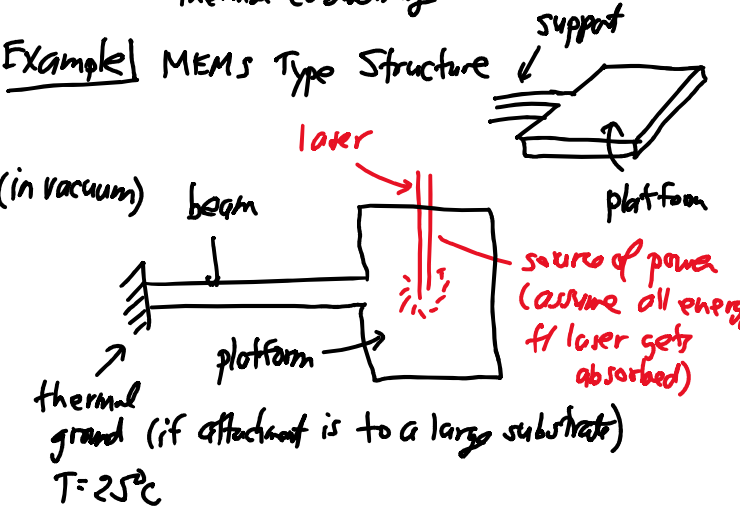
ρ ← density
 V ← volume
 C_p ← specific heat
 → store thermal energy

⇒ thermal resistance:

$R_{th} = \frac{l}{kA}$

l ← length
 kA ← cross-sectional area
 k ← thermal conductivity

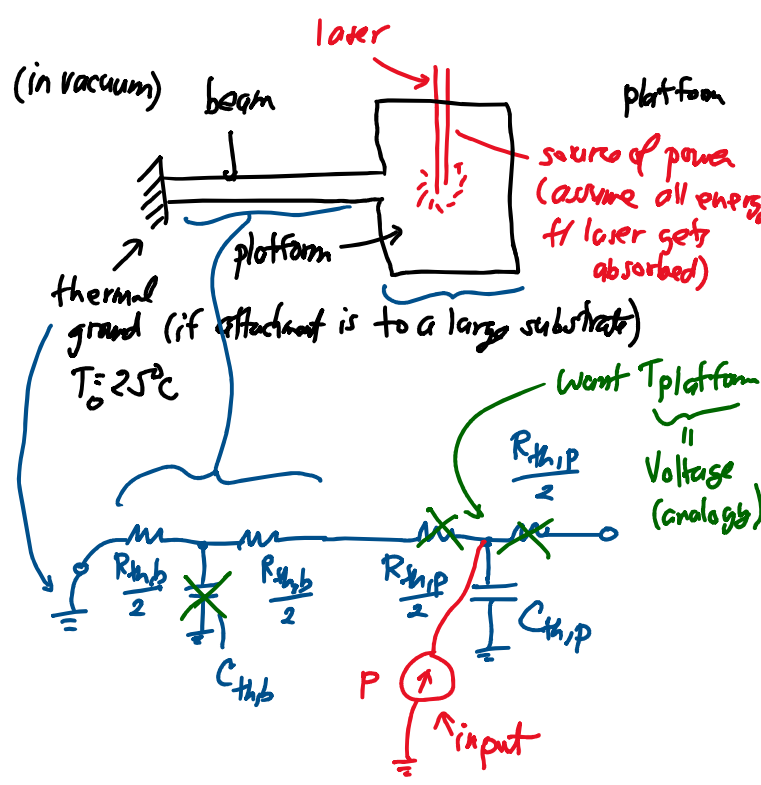
Example MEMS Type Structure



(in vacuum) beam platform support layer source of power (assume all energy of layer gets absorbed) thermal ground (if attachment is to a large substrate) $T_0 = 25^\circ\text{C}$

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What is the temperature on the platform?



(in vacuum) beam platform layer source of power (assume all energy of layer gets absorbed) thermal ground (if attachment is to a large substrate) $T_0 = 25^\circ\text{C}$ $R_{th,b}$ $R_{th,p}$ $C_{th,p}$ P input $T_{platform}$ Voltage (analogous)

Analogies

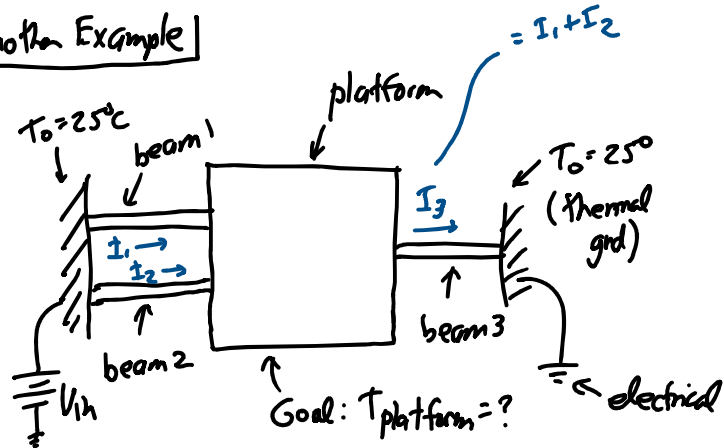
(temperature) $T \rightarrow V$ (voltage)
 (power) $P \rightarrow I$ (current)
 thermal \leftarrow electrical

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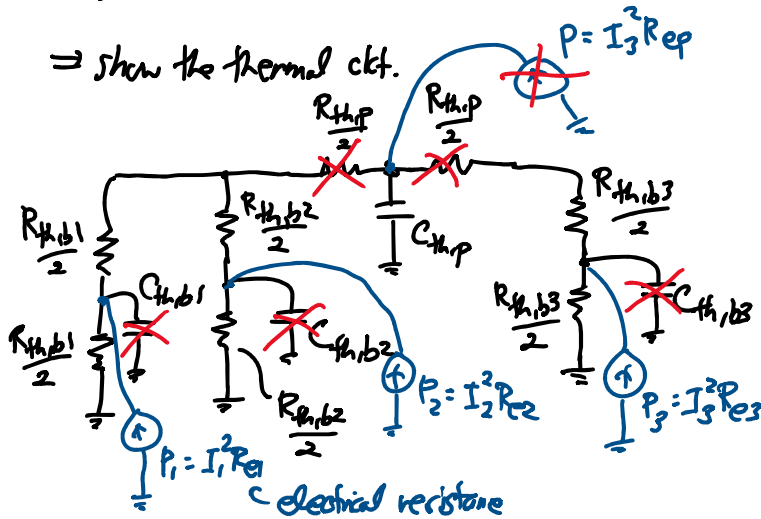
To Analyze:

- ① Remove small elements to simplify the ckt.
- ② $(T_{\text{platform}} - T_0) = PR_{th,b}$ (in steady-state)
 (just like $V=IR$ in an electrical system)

Another Example



\Rightarrow show the thermal ckt.



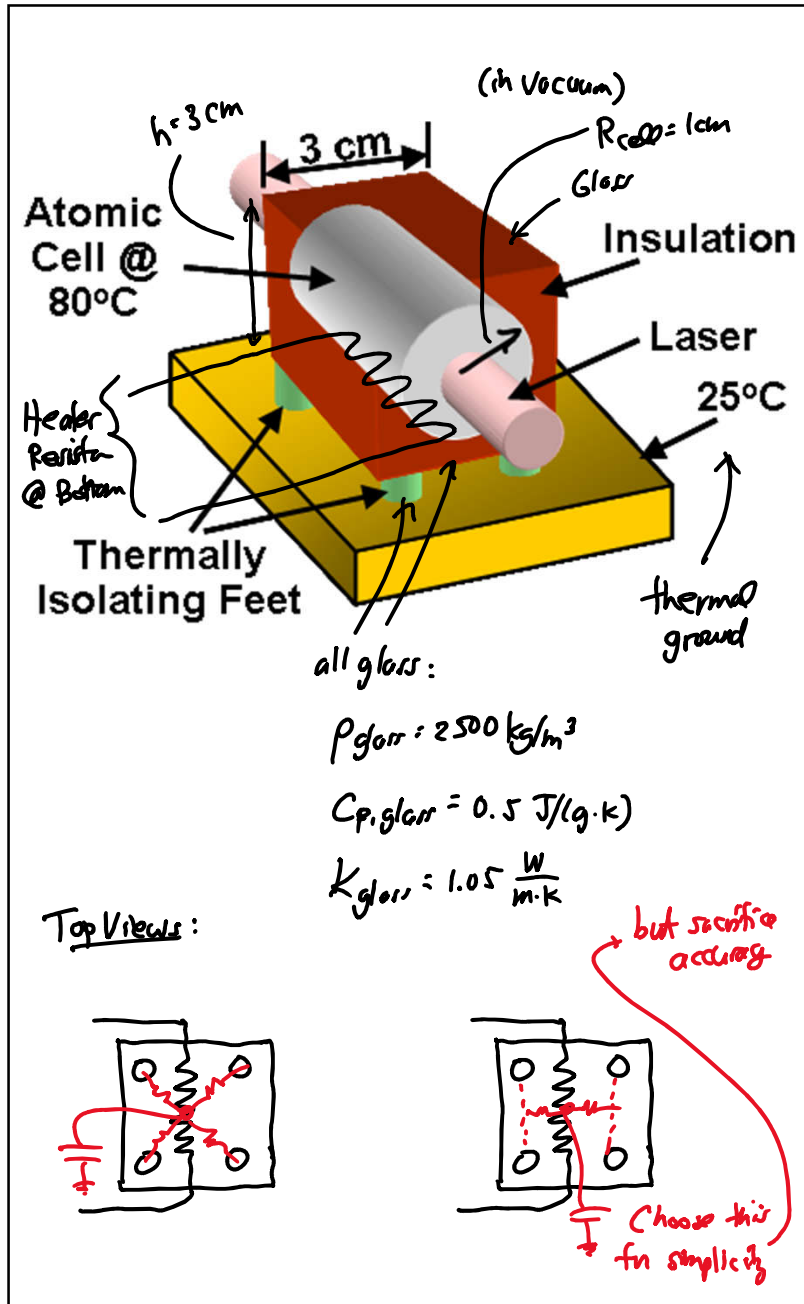
To Analyze:

- ① $I_3 = I_1 + I_2 = \frac{V_{in}}{R_{e,tot}}$ (electrical analysis)
- ② Get P_i 's. (powers)
- ③ Use superposition to solve the thermal ckt.

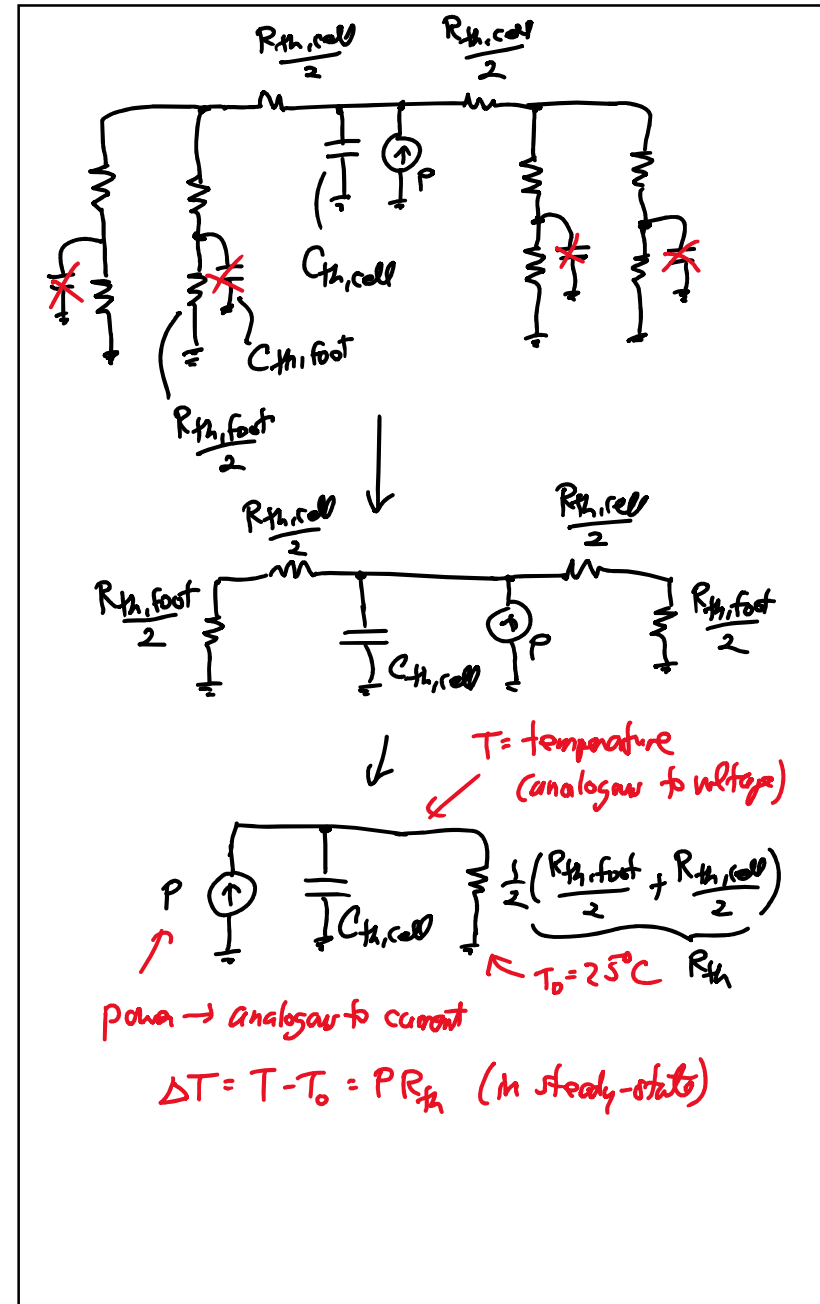
handles one power source at a time
 $\frac{1}{2}$ sum the temperatures (i.e., thermal voltages) to get the total temperature at any point (or node)

Example] Thermal Ckt. for the Cs137 Physics Package

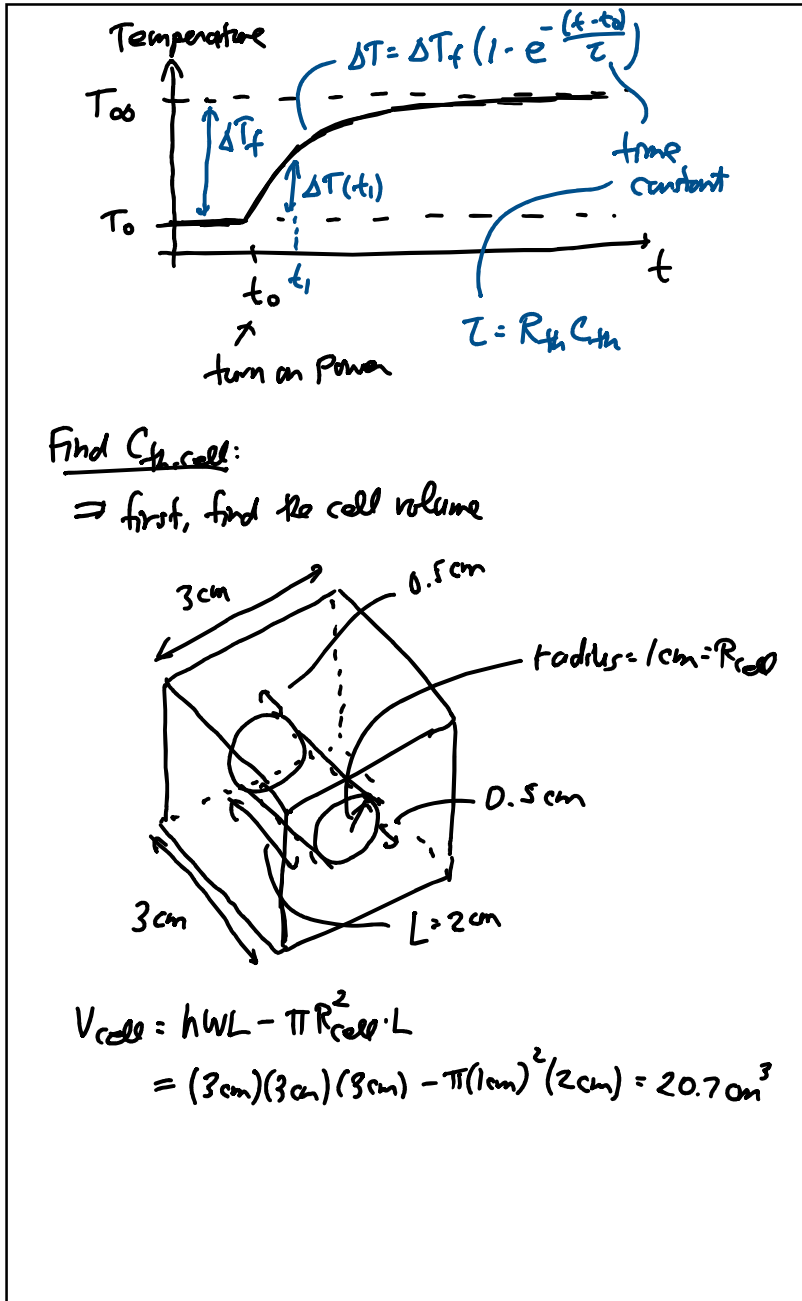
\Rightarrow determine the power needed to get the atomic cell to 80°C (from room temperature)
 $\frac{1}{2}$ how fast



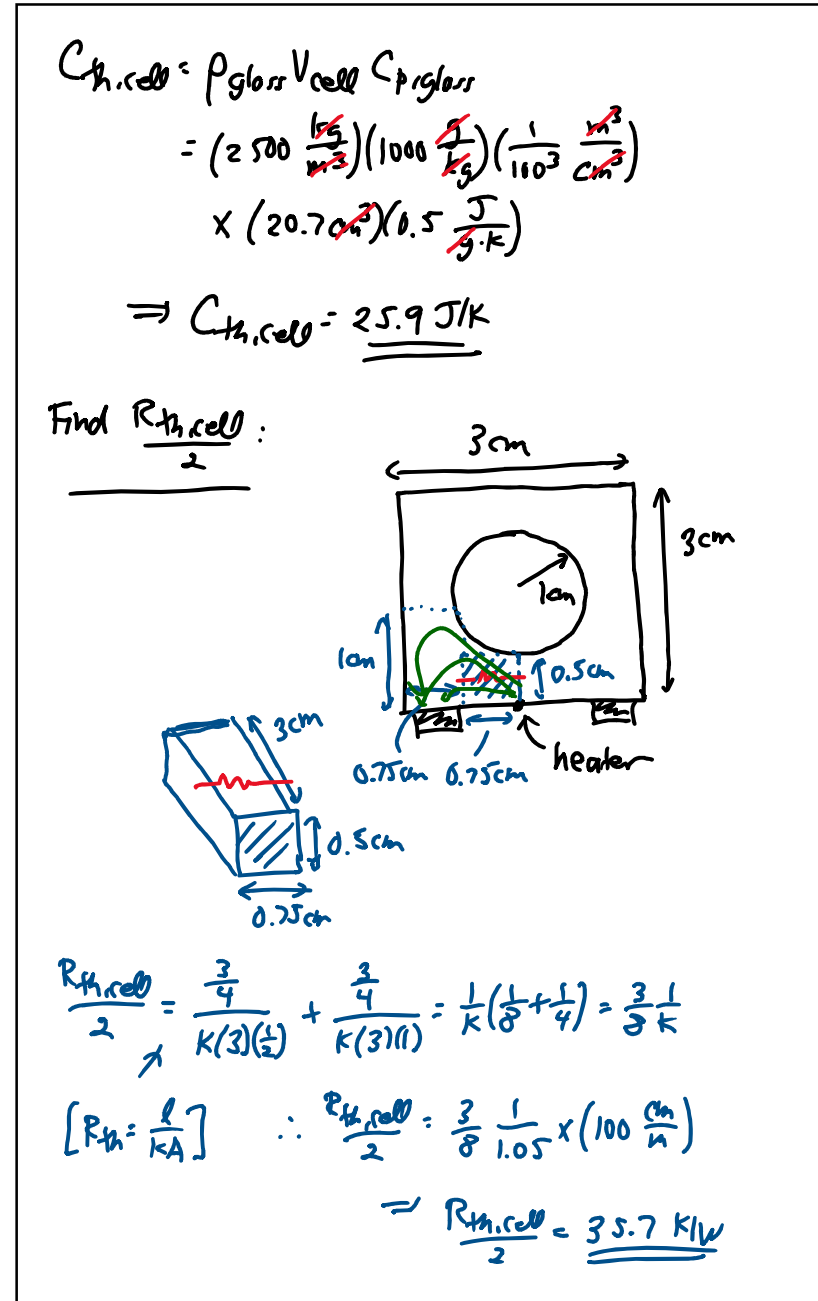
7



8

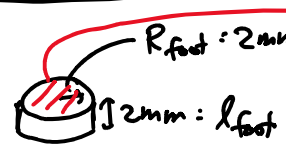


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Find $R_{th,foot}$:



$R_{foot} = 2mm$ $A_{foot} = \pi R_{foot}^2$
 $2mm = l_{foot}$

$$\therefore R_{th,foot} = \frac{l_{foot}}{kA_{foot}} = \frac{2mm}{(1.05 \frac{W}{m \cdot K}) \pi (2mm)^2} = 151.6 \frac{K}{W}$$

Then:

$$R_{th} = \frac{1}{2} \left(\frac{R_{th,foot}}{2} + \frac{R_{th,cell}}{2} \right)$$

$$= \frac{1}{2} \left(\frac{151.6}{2} + 35.7 \right) \Rightarrow R_{th} = \underline{\underline{55.8 \text{ K/W}}}$$

\Rightarrow Find the power req'd to maintain $T_{cell} = 80^\circ C$ in steady-state:

$$P = \frac{T_{cell} - T_0}{R_{th}} = \frac{(80 - 25)}{55.8} = 0.99W \sim \textcircled{1W}$$

\Rightarrow Find the time constant:

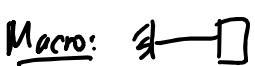
$$\tau = R_{th} C_{th,cell} = (55.8) (25.9) = \textcircled{24 \text{ min.}}$$

\rightarrow It takes $\sim 3\tau$ to reach steady-state
 \therefore must wait 72 min. before using this atomic cell


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How about using MEMS?

\hookrightarrow (how about scaling this?)
 \Rightarrow much smaller cell volume \rightarrow weight \downarrow
 $U_d \rightarrow C_{th}$

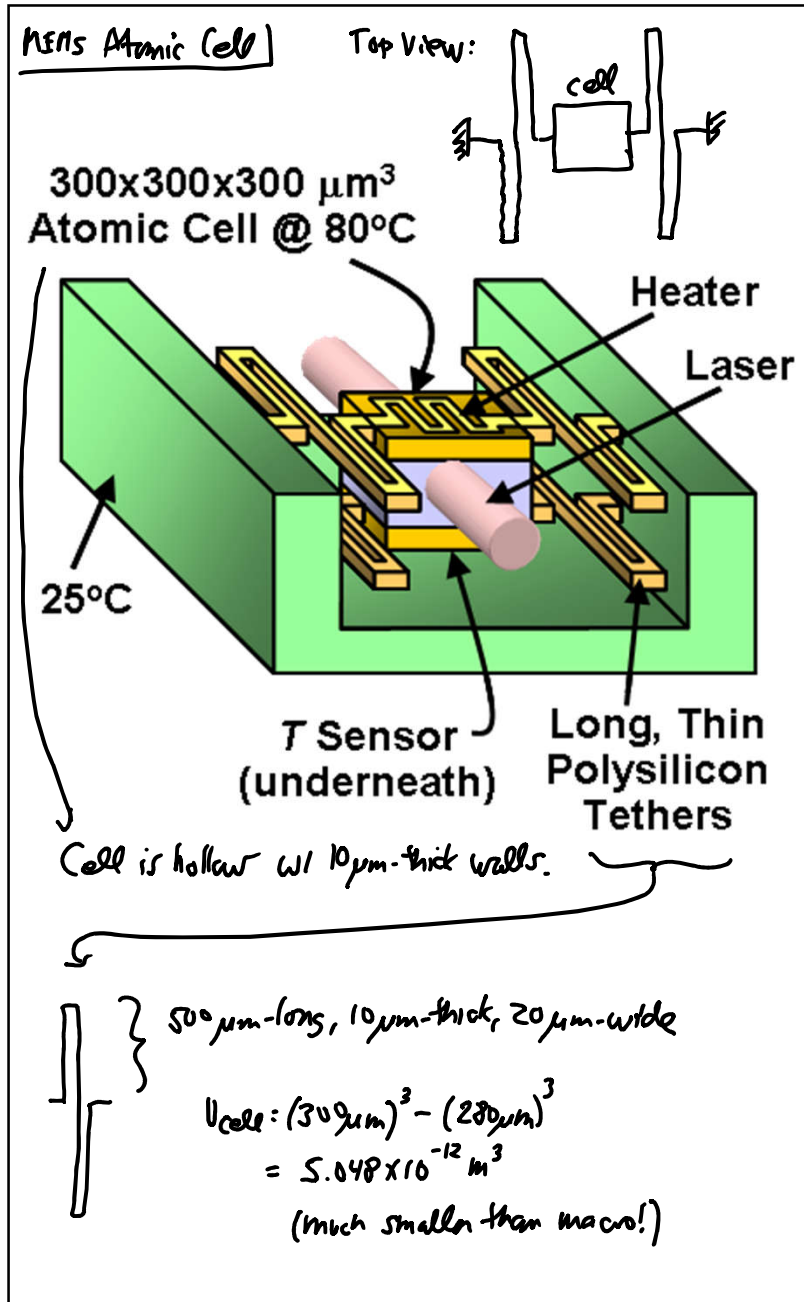
Macro: 

\downarrow shrink dimensions

Micro: 

Can do this \rightarrow use long, thin support to suspend a smaller cell

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$$C_{th, \text{cell}} = \rho_{\text{glass}} V_{\text{cell}} C_{p, \text{glass}}$$

$$= (2500 \frac{\text{kg}}{\text{m}^3}) (5.048 \times 10^{-12} \text{ m}^3) (500 \frac{\text{J}}{\text{kg} \cdot \text{K}})$$

$$= 6.31 \times 10^{-6} \frac{\text{J}}{\text{K}} \leftarrow 4 \text{ million} \times \text{smaller than macro!}$$

$$R_{th, \text{supp}} = \frac{l_{\text{supp}}}{k_{\text{polySi}} W_{\text{supp}} h_{\text{supp}}} = \frac{500 \mu\text{m}}{(30 \frac{\text{W}}{\text{m} \cdot \text{K}}) (20 \mu\text{m}) (10 \mu\text{m})}$$

$$\Rightarrow R_{th, \text{supp}} = \underline{\underline{83,333 \text{ kW}}}$$

\uparrow 1493x larger than macro!

and...

$$P = \frac{(80-25)}{83,333} = \underline{\underline{0.66 \text{ mW}}} \leftarrow 1493 \times \text{smaller than macro!}$$

$$\tau = \underline{\underline{0.53 \text{ s}}} \leftarrow 2727 \times \text{faster!}$$

All due to scaling!